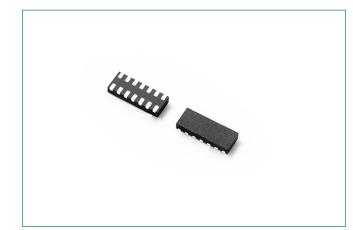
TVS Diode Array Datasheet

SP3012 Series 0.5pF Diode Array for USB3.0





Additional Information



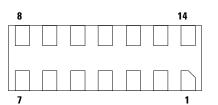


Resources

Accessories

Samples

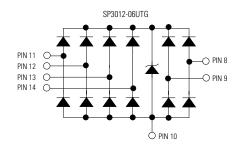
Pinout



SP3012-06UTG (AEC-Q101 Qualified) *Pins 1, 2, 3, 4, 5, 6, 7 are not internally connected

but should be connected to the opposite pin with the PCB trace

Functional Block Diagram



Life Support Note:

Not Intended for Use in Life Support or Life Saving Applications

The products shown herein are not designed for use in life sustaining or life saving applications unless otherwise expressly indicated.



Description

The SP3012 Series integrates 6 channels of ultra low capacitance rail-to-rail diodes and an additional zener diode to provide protection for electronic equipment that may experience destructive electrostatic discharges (ESD). These robust devices can safely absorb repetitive ESD strikes above the maximum level specified in the IEC 61000-4-2 international standard (±8kV contact discharge) without performance degradation.

The extremely low loading capacitance also makes it ideal for protecting high speed signal lines such as USB3.0, HDMI, USB2.0, and eSATA.

Features

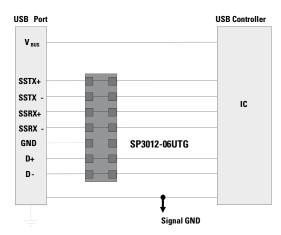
- ESD, IEC 61000-4-2, ±12kV contact, ±25kV air
- EFT, IEC 61000-4-4, 40A (tP=5/50ns)
- Lightning, IEC 61000-4-5 2nd edition, 4A (tP=8/20µs)
- Low capacitance of 0.5pF (TYP) per I/O
- Low leakage current of 1.5µA (MAX) at 5V

Applications

- LCD/PDPTVs
- External Storages
- DVD/Blu-ray Players
- Desktops
- MP3/PMP

- Small form factor µDFN (JEDEC MO-229) package provides flow through routing to simplify PCB layout
- AEC-Q101 Qaulified
- Halogen free, lead free and RoHS compliant
- Set Top Boxes
- Smartphones
- Ultrabooks/Notebooks
- Digital Cameras
- Automotive Electronics

Application Example for USB3.0



Absolute Maximum Ratings

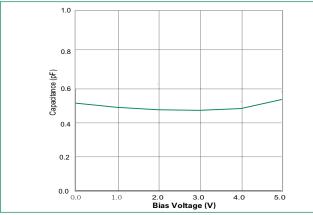
Symbol	Parameter	Value	Units
I _{PP}	Peak Current (t _p =8/20µs)	4.0	А
Т _{ор}	Operating Temperature	-40 to 125	°C
T _{stor}	Storage Temperature	-55 to 150	°C

Caution: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

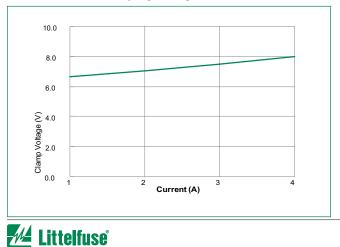
			UP 1			
Parameter	Symbol	Test Conditions	Min	Тур	Max	Units
Reverse Standoff Voltage	V _{RWM}	$I_{R} \leq 1\mu A$			5.0	V
Breakdown Voltage	V _{BR}	I _R = 1mA	6.0			V
Reverse Leakage Current	I _{LEAK}	V _R =5V, Any I/O to GND			1.5	μΑ
Clamp Voltage ¹ V _c	V	I_{pp} =1A, t_p =8/20µs, Fwd		6.6	7.9	V
	V _C	$I_{pp}=2A$, $t_p=8/20\mu s$, Fwd		7.0	8.4	V
Dynamic Resistance	R _{DYN}	(V _{C2} - V _{C1}) / (I _{PP2} - I _{PP1})		0.4		Ω
ESD Withstand Voltage ¹ V _{ESD}	V	IEC61000-4-2 (Contact)	±12			kV
	V _{ESD}	IEC61000-4-2 (Air)	±25			kV
Diode Capacitance ¹	C _{I/O-GND}	Reverse Bias=0V, f=1 MHz		0.5	0.65	pF
Diode Capacitance ¹	C _{I/O-/O}	Reverse Bias=0V, f=1 MHz		0.3	0.4	pF

Note: ¹ Parameter is guaranteed by design and/or device characterization.

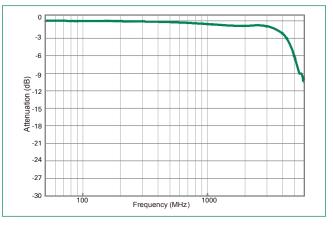




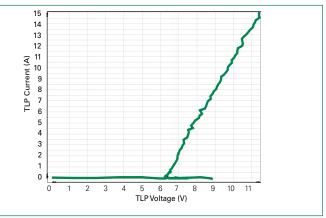
Clamping Voltage vs. IPP



Insertion Loss (S21) I/O to GND



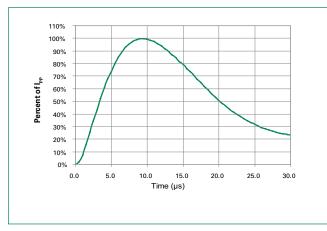
Transmission Line Pulsing(TLP) Plot



TVS Diode Array Datasheet

SP3012 Series 0.5pF Diode Array for USB3.0

Pulse Waveform



Product Characteristics

Lead Plating	Pre-Plated Frame (µDFN)	
Lead Material	Copper Alloy	
Lead Coplanarity	0.0004 inches (0.102mm)	
Substrate Material	Silicon	
Body Material	Molding Compound	
Flammability	UL Recognized compound meeting flammability rating V-0	

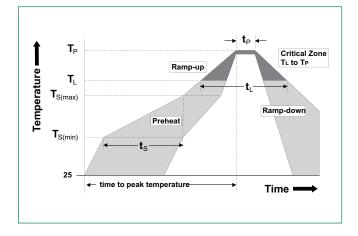
Notes :

All dimensions are in millimeters
Dimensions include solder plating.

3. Dimensions are exclusive of mold flash & metal burr. Blo is facing up for mold and facing down for trim/form, i.e. reverse trim/form.
Package surface matte finish VDI 11-13.

Soldering Parameters

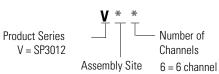
Reflow Condition		Pb – Free assembly	
	- Temperature Min (T _{s(min)})	150°C	
Pre Heat	- Temperature Max (T _{s(max)})	200°C	
	- Time (min to max) (t _s)	60 - 120 secs	
Average ramp up rate (Liquidus) Temp (T_L) to peak		3°C/second max	
T _{S(max)} to T _L - Ramp-up Rate		3°C/second max	
Reflow	- Temperature (T _L) (Liquidus)	217°C	
	- Temperature (t _L)	60 – 150 seconds	
Peak Temperature (T _P)		260 ^{+0/-5} °C	
Time within 5°C of actual peak Temperature (t _p)		30 seconds	
Ramp-down Rate		6°C/second max	
Time 25°C to peak Temperature (T _P)		8 minutes Max.	
Do not exceed		260°C	



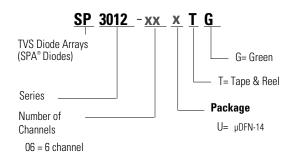
Ordering Information

Part Number	Package	Min. Order Qty.
SP3012-06UTG	µDFN-14	3000

Part Marking System



Part Numbering System





SP3012 Series 0.5pF Diode Array for USB3.0

Application Information

Signal Integrity of High-Speed Data Interfaces

Figure 1: PCB Layout of the SP3012-06UTG for USB 3.0

Adding external ESD protection to a high-speed data port is not trivial for a variety of reasons.

1. ESD protection devices will add parasitic capacitance to each data line from line to GND and line to line causing impedance mismatches between the differential pairs. This ultimately affects the signal eye-diagram and whether or not the transceiver can distinguish a "1" from a "0".

2. ESD devices should be placed as close as possible to the port being protected to maximize their effect (i.e. clamping capability) and minimize the effect that PCB trace inductance can have during an ESD transient. Depending on the package size and pinout this could be challenging and the bigger the package, the larger the land pattern must be, which adds more parasitic capacitance.

3. Stub traces can add another element of discontinuity adversely affecting signal integrity so ESD protection is best employed when it's "overlaid" on the data lines or when the signals can simply pass underneath the device.

Taking all of this into account Littelfuse developed the SP3012 Series which was designed specifically for protection of high-speed data ports such as HDMI 1.3/1.4 and USB 3.0. They present less than 0.5pF from line to GND and only 0.3pF from line to line minimizing impedance mismatch between the differential pairs.

Furthermore, the SP3012 is rated up to ± 12 kV (contact discharge) which far exceeds the maximum requirement of the IEC 61000-4-2 standard.

SP3012-06UTG is housed in leadless μ DFN packages so the data lines can pass directly underneath the device to reduce discontinuities and maintain signal integrity.

USB 3.0 Eye Diagram Data

Figure 1 shows the layout used for the SP3012-06UTG in a USB 3.0 application. The traces routed toward the top are the two legacy USB 2.0 lines (D+/D-) that run at the slower speed of 480Mbps and therefore are not as critical as the 5Gbps Super-Speed traces.

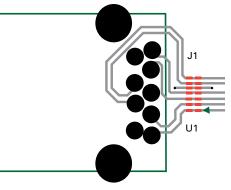


Figure 2 shows the USB 3.0 eye diagram that resulted from the PCB layout above with the SP3012-06UTG soldered on the landing pattern.

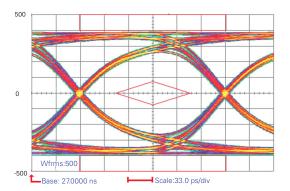


Figure 2: USB 3.0 Eye Diagram with the SP3012-06UTG



Inches

Nom

0.020

0.001

0.008

0.138

0.054

_

0.012

0.020 BSC

0.008 Ref

Max

0.022

0.002

0.012

0.142

0.058

-

0.014

Min

0.018

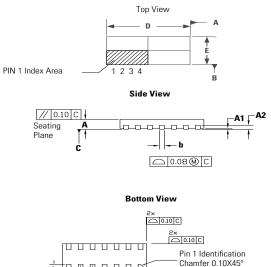
0.000

0.006

0.134

0.050

0.010



Package Dimensions – µDFN-14 (3.5x1.35x0.5mm)

Symbol

Α

A1

A2

b

D

D2

Е

E1

е

L

Notes:



Dimension and tolerancing comform to ASME Y14.5M-1994. 2. Controlling dimensions: Millimeter. Converted Inch dimensions are not necessarily exact.

Soldering Pad Layout Dimensions			
Symbol	Millimeters	Inches	
	Nom	Nom	
D	3.30	0.1299	
E	1.65	0.0571	
b	0.30	0.0118	
L	0.50	0.0197	
е	0.50 typ	0.020 typ	
S	0.20	0.0078	
s1	0.65	0.0256	

µDFN-14 (3.5x1.35x0.5mm) JEDEC MO-229

Max

0.55

0.05

0.25

3.60

1.45

_

0.35

Millimeters

Nom

0.50

0.02

0.203 Ref

0.20

3.50

1.35

_

0.500 BSC

0.30

Min

0.45

0.00

0.15

3.40

1.25

-

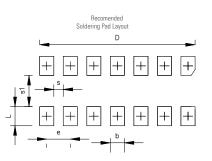
0.25

⊕ 0.10 M C A B

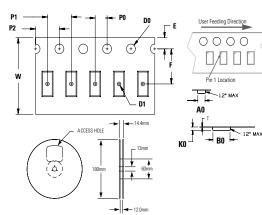
321

Π

- e -



Embossed Carrier Tape & Reel Specification - µDFN-14



Symbol	Millimeters	
A0	1.58 +/- 0.10	
B0	3.73 +/- 0.10	
D0	Ø 1.50 + 0.10	
D1	Ø 0.60 +/- 0.05	
E	1.75 +/- 0.10	
F	5.50 +/- 0.05	
KO	0.68 + 0.12/ -0.10	
P0	2.00 +/- 0.05	
P1	4.00 +/- 0.10	
P2	4.00 +/- 0.10	
т	0.28 +0.02/ -0.05	
W	12.00 + 0.30 /- 0.10	

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